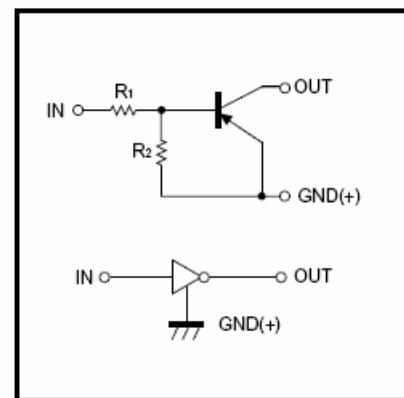


Features

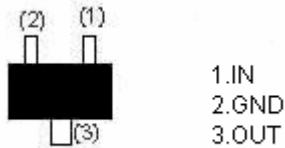
- 1) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors(see equivalent circuit).
- 2) The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
- 3) Only the on/off conditions need to be set for operation, making device design easy.

●Equivalent circuit



PIN CONNECTIONS AND MARKING

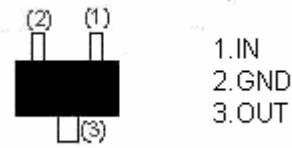
DTA123JE



SOT-523

Addreviated symbol: E32

DTA123JUA



DTA123JKA



SOT-23-3L

Addreviated symbol: E32

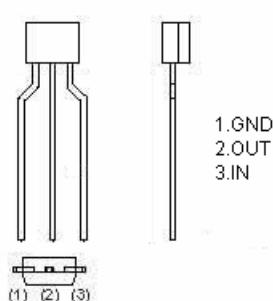
DTA123JCA



SOT-23

Addreviated symbol: E32

DTA123JSA



TO-92S

Absolute maximum ratings(Ta=25°C)

Digital Transistor(PNP)

Parameter	Symbol	Limits (DTA123J□)					Unit
		E	UA	KA	CA	SA	
Supply voltage	V _{CC}			-50			V
Input voltage	V _{IN}			-12~+5			V
Output current	I _O			-100			mA
	I _{C(MAX)}			-100			
Power dissipation	P _d	150		200		300	mW
Junction temperature	T _j			150			°C
Storage temperature	T _{stg}			-55~150			°C

Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ	Max.	Unit	Conditions
Input voltage	V _{I(off)}			-0.5	V	V _{CC} =-5V, I _O =-100μA
	V _{I(on)}	-1.1				V _O =-0.3V, I _O =-5mA
Output voltage	V _{O(on)}		-0.1	-0.3	V	I _O /I _I =-5mA/-0.25mA
Input current	I _I			-3.6	mA	V _I =-5V
Output current	I _{O(off)}			-0.5	μA	V _{CC} =-50V, V _I =0
DC current gain	G _I	80				V _O =-5V, I _O =-10mA
Input resistance	R ₁	1.54	2.2	2.86	KΩ	-
Resistance ratio	R _{2/R₁}	17	21	26		-
Transition frequency	f _T		250		MHz	V _O =-10V, I _O =-5mA, f=100MHz

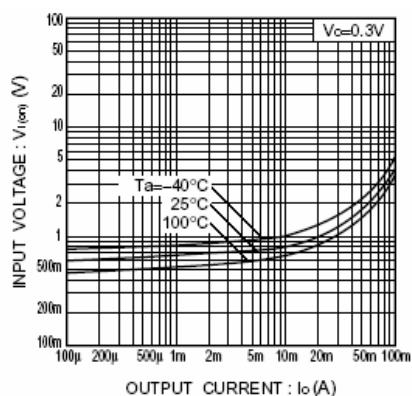
Typical Characteristics


Fig.1 Input voltage vs. output current (ON characteristics)

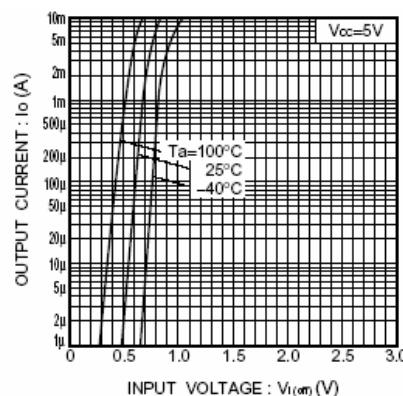


Fig.2 Output current vs. input voltage (OFF characteristics)

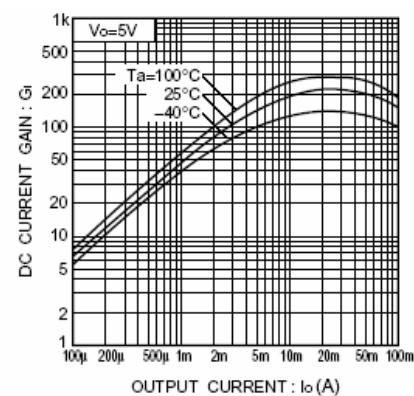


Fig.3 DC current gain vs. output current

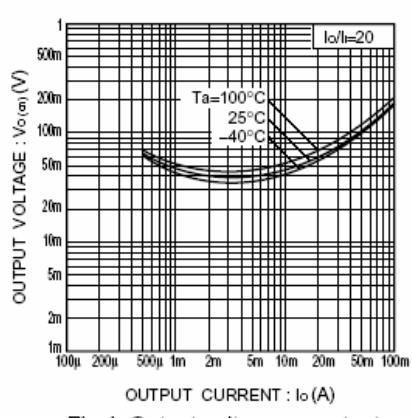


Fig.4 Output voltage vs. output current